## NSN 5961-00-098-8706

Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
2.637 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
1.227 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
10.0 drain supply voltage
Current Rating Per Characteristic:
55.00 amperes forward current, total rms horsepower metric
Power Rating Per Characteristic:
5.0 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
2 tab, solder lug and 1 threaded stud
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0